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#### DATA SHEET

# RENESAS $\mu PD6121, 6122$

### REMOTE CONTROL TRANSMISSION CMOS IC

The μPD6121, 6122 are infrared remote control transmission ICs using the NEC transmission format that are ideally suited for TVs, VCRs, audio equipment, air conditioners, etc. By combining external diodes and resistors, a maximum of 65,536 custom codes can be specified. These ICs come in small packages, thus facilitating the design of light and compact remote control transmitters.

The NEC transmission format consists of leader codes, custom codes (16 bits), and data codes (16 bits). It can be used for various systems through decoding by a microcontroller.

#### FEATURES

- Low-voltage operation: VDD = 2.0 to 3.3 V
- Low current dissipation: 1 μA Max. (at standby)
- Custom codes: 65,536 (set by external diodes and resistors)
- Data codes:
  - μPD6121: 32 codes (single input), 3 codes (double input), expandable up to 64 codes through SEL pin
  - μPD6122: 64 codes (single input), 3 codes (double input), expandable up to 128 codes through SEL pin
- μPD6121, 6122 are transmission code-compatible (NEC transmission format) with the μPD1913C<sup>Note</sup>, 1943G<sup>Note</sup>, 6102G<sup>Note</sup>, and 6120C<sup>Note</sup>.
- Pin compatibility:
  - μPD6121G-001 is pin-compatible with the μPD1943G (However, capacitance of capacitor connected to oscillator pin and other parameters vary)
  - μPD6122G-001 is pin-compatible with the μPD6102G (However, capacitance of capacitor connected to oscillator pin and other parameters vary)
- Standard products (Ver. I, Ver. II specifications)

Note Provided for maintenance purpose only

- When using this product (in NEC transmission format), please order custom codes from NEC.
- New custom codes for the  $\mu\text{PD6121G-002},\,\mu\text{PD6122G-002}$  cannot be ordered.

\*

### μ**PD6121, 6122**

#### \* ORDERING INFORMATION

Part number	Package	Description
μPD6121G-001	20-pin plastic SOP (375 mil)	Standard (Ver I spec.)
μPD6121G-002	20-pin plastic SOP (375 mil)	Standard (Ver II spec.)
μPD6122G-001	24-pin plastic SOP (375 mil)	Standard (Ver I spec.)
μPD6122G-002	24-pin plastic SOP (375 mil)	Standard (Ver II spec.)

**Phase-out/Discontinued** 

#### PIN CONFIGURATION (Top View)







#### PIN IDENTIFICATIONS

CCS :	Custom code selection input
KI0 - KI7 :	Key input
KI/O0 - KI/O7 :	Key input/output
LMP :	Lamp output
OSCI, OSCO:	Resonator connection pin

REM :	Remote	output
-------	--------	--------

SEL : SEL input

- VDD : Power supply pin
- Vss : GND pin

#### μ**PD6121, 6122**

\*

#### **BLOCK DIAGRAM**



Phase-out/Discontinued

Note  $\mu$ PD6121: KI<sub>0</sub> - KI<sub>3</sub>  $\mu$ PD6122: KI<sub>0</sub> - KI<sub>7</sub>

#### DIFFERENCES BETWEEN PRODUCTS

Part number Item	μPD6121	μPD6122					
Operating voltage	VDD = 2.0	0 to 3.3 V					
Current consumption (at standby)	1 μΑ	MAX.					
Custom codes	65,536 (16-bit setting)						
Data codes	32 x 2	64 x 2					
No. of KI pins	4	8					
No. of KI/O pins	8						
SEL pin	Provided						
Transmission format	NEC transm	ission format					
Package	20-pin plastic SOP (375 mil)	24-pin plastic SOP (375 mil)					

#### 1. PIN FUNCTIONS

#### (1) Key input pins (Klo to Kl7), key input/output pins (Kl/Oo to Kl/O7)

A pull-down resistor is placed between key input pins and a Vss pin. When several keys are pressed simultaneously, the transmission of the corresponding signals is inhibited by a multiple-input prevention circuit. In the case of double-key input, transmission is inhibited if both keys are pressed simultaneously (within 36 ms interval); if not pressed simultaneously, the priority of transmission is first key, then second key. When a key is pressed, the custom code and data code reading is initiated, and 36 ms later, output to REM output is initiated. Thus if the key is pressed during the initial 36 ms, one transmission is performed. If a key is kept pressed for 108 ms or longer, only leader codes are consecutively transmitted until the key is released. Keys can be operated intermittently at intervals as short as 126 ms (interval between two on's), making this an

Phase-out/Discontinued

### (2) Resonator connection pins (OSCI, OSCO)

extremely fast-response system.

The oscillator starts operating when it receives a key input. Use a ceramic resonator with a frequency between 400 and 500 kHz.

#### (3) Power-supply pin

The power supply voltage is supplied by two 3-V batteries. A broad range of operating power supply voltage is allowed, from 2.0 to 3.3 V. The supply current falls below 1  $\mu$ A when the oscillator is inactive when no keys are pressed.

#### (4) REM output pin

The REM output pin outputs the transmission code, which consists of the leader code, custom code (16 bits), and data code (16 bits) (Refer to **2. NEC TRANSMISSION FORMAT (REM OUTPUT)**).

#### (5) SEL input pin

By controlling D<sub>7</sub> of the data code with this pin, the  $\mu$ PD6121 and  $\mu$ PD6122 can transmit 64 and 128 different data codes, respectively. By connecting the SEL pin to V<sub>DD</sub> or Vss, D<sub>7</sub> is set to "0" or "1", respectively. This pin has high-impedance input, therefore be sure to connect it either to V<sub>DD</sub> or Vss.

#### (6) CCS input pin

By placing a diode between the CCS pin and the KI/O pin, it is possible to set a custom code. When a diode is connected, the corresponding custom code is "1", and when not connected, it is "0".

#### (7) LMP output pin

The LMP pin outputs a low-level signal while the REM pin outputs a transmission code.

#### 2. NEC TRANSMISSION FORMAT (REM OUTPUT)

The NEC transmission format consists of the transmission of a leader code, 16-bit custom codes (Custom Code, Custom Code), and 16-bit data codes (Data Code, Data Code) at one time, as shown in Figure 2-1.

Phase-out/Discontinued

Also refer to 4. REMOTE OUTPUT WAVEFORM.

Data Code is the inverted code of Data Code.

The leader code consists of a 9-ms carrier waveform and a 4.5-ms OFF waveform and is used as leader for the ensuing code to facilitate reception detection.

Codes use the PPM (Pulse Position Modulation) method, and the signals "1" and "0" are fixed by the interval between pulses.



Figure 2-1. REM Output Code

- Cautions 1. Use any of the possible 256 kinds of custom codes specified with 00xxH (diode not connected), as desired. If intending to use custom codes other than 00xxH, please consult NEC in order to avoid various types of errors from occurring between systems.
  - When receiving data in the NEC transmission format, check that the 32 bits made up of the 16-bit custom code (Custom Code, Custom Code') and the 16-bit data code (Data Code, Data Code) are fully decoded, and that there are no signals with the 33rd bit and after (be sure to check also Data Code).



#### \* 3. CUSTOM CODE (CUSTOM CODE, CUSTOM CODE') SETTING

The custom code is set in two different ways depending on whether Ver I or Ver II specifications are employed.

Figure	3-1.	Custom	Code	Setting
--------	------	--------	------	---------

	Higher 8 bits of custom code	Lower 8 bits of custom code'
Ver I	Fixed by external diode bit	Fixed by external pull-up resistor bit
Ver II	<ul> <li>C<sub>0</sub>, C<sub>1</sub>, C<sub>2</sub> Fixed by connecting CCS pin and either one of pins KI/O<sub>0</sub> to KI/O<sub>7</sub></li> <li>C<sub>3</sub> to C<sub>7</sub> Fixed by absence or presence of external pull-up resistor for KI/O<sub>6</sub>, KI/O<sub>7</sub></li> </ul>	Fixed by external pull-up resistor (KI/O <sub>0</sub> to KI/O <sub>5</sub> ) bit

**Remark** The  $\mu$ PD6121-001 has Ver I specifications and is pin-compatible with the  $\mu$ PD1943G, and the  $\mu$ PD6122-001 has Ver I specifications and is pin-compatible with the  $\mu$ PD6102G.

If used as pin-compatible products, please note the following points.

- (1) Connect the SEL pin to VDD.
- (2) Change the capacitance of the capacitor connected to the resonator connection pin (Refer to
   9. ELECTRICAL SPECIFICATIONS).

A custom code setting example is shown below.

#### \* 3.1 Standard versions with Ver I specs. (μPD6121-001, μPD6122-001)

Each of the higher 8 bits of the custom code is set to "1" when a diode is connected between the CCS pin and the corresponding KI/O pin, and is set to "0" when no diode is connected. If a pull-up resistor is connected to the KI/O pin corresponding to one of the lower 8 bits of the custom code', the bit is first set to "1". Based on the 1's information of the lower 8 bits of the custom code', the corresponding bit of the higher 8 bits of the custom code is then captured and not inverted. The non-inverted value is finally overwritten to the corresponding bit of the lower 8 bits of the custom code'. The inverse occurs when no pull-up resistor is connected.

It follows from the above that the custom code can be set in 65,536 different ways depending on whether or not a diode and/or pull-up resistor are present.

Please refer to Figure 3-2 Example of Custom Code Setting for Ver I Specifications (µPD6121-001, 6122-001).

Figure 3-2. Example of Custom Code Setting for Ver I Specifications (µPD6121-001, 6122-001)

#### Configuration example



The higher 8 bits of the custom code are determined by the diode connected to the CCS pin and KI/O pin. Set custom code

Phase-out/Discontinued



The inversion/non-inversion of the lower 8 bits of the custom code' is determined by the pull-up resistor connected to the KI/O pin.

Set custom code



When the above-described setting is done, the following custom code is output. Custom code

	Hig	gher	8 b	its c	of cu	istor	n co	Lov	ver	8 bit	ts of	cus	stom		de'	
	1 0 0 0 1 0 1 0						1	1	1	1	1	1	0	1		
_	$C_0$	$C_1$	$C_2$	C <sub>3</sub>	$C_4$	$C_5$	$C_6$	<b>C</b> 7	Co'	C1'	<b>C</b> <sub>2</sub> '	C₃'	C4'	<b>C</b> 5'	C6'	C7'
									C <sub>0</sub>	$\overline{C_1}$	$\overline{C}_2$	<del>C</del> <sub>3</sub>	<b>C</b> <sub>4</sub>	$\overline{C}_{5}$	$\overline{C}_{6}$	$\overline{C_7}$

Remark Codes are transmitted from the LSB.

\*

#### \* 3.2 Standard versions with Ver II specs. (μPD6121-002, 6122-002)

In Ver II, the CCS pin does not have the external diode reading function.

The allocation of C<sub>2</sub>, C<sub>1</sub> and C<sub>0</sub> of the higher 8 bits of the custom code is done by connecting the CCS pin to any one of the KI/O<sub>0</sub> to KI/O<sub>7</sub> pins, as shown below.

**Phase-out/Discontinued** 

Pin connected to CCS pin	<b>C</b> <sub>2</sub>	C <sub>1</sub>	<b>C</b> <sub>0</sub>
KI/O <sub>0</sub>	0	0	0
KI/O1	0	0	1
KI/O2	0	1	0
KI/O3	0	1	1
KI/O4	1	0	0
KI/O5	1	0	1
KI/O <sub>6</sub>	1	1	0
KI/O7	1	1	1

When CCS pin is open,  $(C_2 C_1 C_0) = (0 0 0)$ 

The allocation of C7, C<sub>6</sub>, C<sub>5</sub>, C<sub>4</sub> and C<sub>3</sub> of the higher 8 bits of the custom code is as follows depending on whether a pull-up resistor is provided.

Pull-up F	Resistor	C7 to	C₃ of Hig	gher 8 bits	of Custor	n Code
KI/O <sub>6</sub>	KI/O7	C7	C <sub>6</sub>	C5	C4	C₃
Not Provided	Not Provided	0	0	0	0	0
Not Provided	Provided	1	0	0	1	1
Provided	Not Provided	1	0	0	0	0
Provided	Provided	1	1	1	0	1

Caution In Ver II, it is not possible to set all custom codes.

Also, new custom codes cannot be ordered for Ver II products; therefore, Ver I products should be used if new custom codes are required.

Figure 3-3. Example of Custom Code Setting for Ver II Specifications (µPD6121-002, 6122-002)

#### **Configuration Example**



C<sub>2</sub>, C<sub>1</sub> and C<sub>0</sub> of the higher 8 bits of the custom code are fixed by connecting the CCS pin to KI/O<sub>0</sub> to KI/O<sub>7</sub>. Therefore, in the configuration example, they become  $1 \ 0 \ 0$ .

 $C_0 C_1 C_2$ 

C7, C6, C5, C4 and C3 of the higher 8 bits of the custom code are selected and fixed by the pull-up resistor connected to  $KI/O_6$  and  $KI/O_7$  in four channels.

_					Pull-up resistor						
<b>C</b> 7	<b>C</b> 6	C <sub>5</sub>	<b>C</b> <sub>4</sub>	C₃	KI/O6	KI/O7					
1	0	1	1	0	Disconnected	Disconnected					
0	0	1	1	1	Disconnected	Connected					
1	1	0	1	1	Connected	Disconnected					
1	1	1	1	1	Connected	Connected					

In this configuration example, C<sub>3</sub> to C<sub>7</sub> of the higher 8 bits of the custom code become  $\boxed{1 \ 1 \ 0 \ 1 \ 1}$ . C<sub>3</sub> C<sub>4</sub> C<sub>5</sub> C<sub>6</sub> C<sub>7</sub>

The inversion/non-inversion of the lower 8 bits of the custom code' is fixed by the bit of the external pullup resistor of KI/O<sub>0</sub> to KI/O<sub>5</sub>.

Lower 8 bits of custom code' 1 0 1 0 0 0 0 0 0 C<sub>0</sub>' C<sub>1</sub>' C<sub>2</sub>' C<sub>3</sub>' C<sub>4</sub>' C<sub>5</sub>' C<sub>6</sub>' C<sub>7</sub>' Pull-up resistor bit (KI/O<sub>0</sub>, KI/O<sub>2</sub>)

External setting (Refer to Configuration Example)

Bit for non-inversion of custom code is set

1: Non-inversion for  $C_0$  to  $C_7$ 0: Inversion for  $C_0$  to  $C_7$ 

Caution C6' and C7' are fixed to 0.

\*

As noted above, setting the pull-up resistor and connection, produces the following custom code. Custom code

*

Higher 8 bits of custom code									Lower 8 bits of custom code'							
1	0	0	1	1	0	1	1		1	1	0	0	0	1	0	0
C <sub>0</sub>	C <sub>1</sub>	<b>C</b> <sub>2</sub>	C₃	<b>C</b> <sub>4</sub>	C <sub>5</sub>	<b>C</b> <sub>6</sub>	<b>C</b> 7		Co'	C1'	C2'	C₃'	C4'	<b>C</b> 5'	<b>C</b> <sub>6</sub> '	C7'
									$C_0$	$\overline{C_1}$	$C_2$	$\overline{C_3}$	$\overline{C_4}$	$\overline{C_5}$	$\overline{C_6}$	$\overline{C_7}$

Remark	Codes	are	transmitted	from	the	LSB.
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- 4. REMOTE OUTPUT WAVEFORM (NEC TRANSMISSION FORMAT: ONE-SHOT COMMAND TRANSMISSION MODE)
- When fosc = 455 kHz
  - (1) Remote (REM) output (from stage (2), transmission occurs only when key is kept depressed)



(3) Magnification of waveform (3)



(4) Magnification of waveform (2)





- Carrier frequency: fc = fosc/12 = 38 kHz
- Remark If a key is kept depressed, the second and subsequent times, only the leader code and the stop bit are transmitted, which allows power savings for the infrared-emitting diode. If a command is issued continuously in the same way the second and subsequent times as the first time, refer to 7. ONE-SHOT/CONTINUOUS COMMAND TRANSMISSION MODE.

μ**PD6121, 6122** 

#### \* 5. KEY DATA CODES (SINGLE INPUT)

		CON	INECT	ION				C	ΑΤΑ (	CODE				NOTEO	1
KEY	Klo	KI1	KI <sub>2</sub>	KI3	KI/O	Do	D1	D2	D3	D4	D5	D <sub>6</sub>	D <sub>7</sub> Note	NOTES	
K1	*					0	0	0	0	0	0	0	0/1		] 1
K2		*			KI/O <sub>0</sub>	1	0	0	0	0	0	0	0/1		
K3 K4			*	*	-	0	1	0	0	0	0	0	0/1		
K4 K5	*					0	0	1	0	0	0	0	0/1		
K6		*			KI/O1	1	0	1	0	0	0	0	0/1	µPD1913C	
K7			*			0	1	1	0	0	0	0	0/1	μPD6120C	
K8				*		1	1	1	0	0	0	0	0/1	J	
K9	*					0	0	0	1	0	0	0	0/1		
K10 K11		*	*		KI/O <sub>2</sub>	1	0	0	1	0	0	0	0/1 0/1		
K12				*	-	1	1	0	1	0	0	0	0/1		
K13	*					0	0	1	1	0	0	0	0/1		-
K14		*			KI/O₃	1	0	1	1	0	0	0	0/1	µPD1913C Unavailable	
K15			*			0	1	1	1	0	0	0	0/1		
K16				*		1	1	1	1	0	0	0	0/1		• µPD6121
K17 K18	*	*			-	0	0	0	0	1	0	0	0/1 0/1		• μPD6122
K10		^	*		KI/O4	0	1	0	0	1	0	0	0/1		
K20				*	-	1	1	0	0	1	0	0	0/1		
K21	*					0	0	1	0	1	0	0	0/1		11
K22		*			KI/O₅	1	0	1	0	1	0	0	0/1		
K23			*			0	1	1	0	1	0	0	0/1		
K24	*			*		1 0	1	1	0	1	0	0	0/1 0/1		41
K25 K26	*	*			-	1	0	0	1	1	0	0	0/1		
K27			*		KI/O <sub>6</sub>	0	1	0	1	1	0	0	0/1		
K28				*	1	1	1	0	1	1	0	0	0/1		
K29	*					0	0	1	1	1	0	0	0/1		
K30		*			KI/07	1	0	1	1	1	0	0	0/1	µPD1913C Unavailable	
K31 K32			*	*		0	1	1	1	1	0	0	0/1 0/1		
N32						1	I				0	0	0/1		- J
KEY	KI4	KI₅	KI6	Kl <sub>7</sub>	KI/O	Do	D1	D <sub>2</sub>	D3	D <sub>4</sub>	D <sub>5</sub>	D <sub>6</sub>	D7	NOTES	
K33	*					0	0	0	0	0	0	1	0/1	μPD1943G	1
K34		*			KI/O₀	1	0	0	0	0	0	1	0/1	μPD1913C	
K35			*			0	1	0	0	0	0	1	0/1		
K36 K37	*			*		0	0	1	0	0	0	1	0/1	μPD6121G μPD1943G	
K38		*				1	0	1	0	0	0	1	0/1		
K39			*		KI/O1	0	1	1	0	0	0	1	0/1	µPD1913C( µPD6120C(	
K40				*	1	1	1	1	0	0	0	1	0/1	μPD6121G	]
K41	*					0	0	0	1	0	0	1	0/1	μPD1943G	
K42		*			KI/O <sub>2</sub>	1 0	0	0	1	0	0	1	0/1	μPD1913C μPD6120C	
K43			*	*	-	1	1	0	1	0	0	1	0/1	μPD6120C	
K44 K45	*					0	0	1	1	0	0	1	0/1	μPD1943G	11
K46		*			KU/O	1	0	1	1	0	0	1	0/1	µPD1913C	
K47		1	*		KI/O₃	0	1	1	1	0	0	1	0/1	µPD6120C	
K48				*		1	1	1	1	0	0	1	0/1	μPD6121G	<b>Φ</b> μPD6122
K49	*					0	0	0	0	1	0	1	0/1	μPD1943G	only
		*			KI/O4	1	0	0	0	1	0	1	0/1	μPD1913C μPD6120C	
K50			+		1 (1) 0 4						0		1		
K51			*	*		0		1			0	1	0/1	uPD6121G	
K51 K52	*		*	*		0 1 0	1	0	0	1	0 0	1	0/1	μPD6121G μPD1943G	
K51	*	*	*	*		1 0 1	1 0 0	0	0 0 0	1 1 1	0 0		0/1 0/1	μPD1943G μPD1913C	
K51 K52 K53 K54 K55	*		*		KI/O5	1 0 1 0	1 0 0 1	0 1 1 1	0 0 0	1 1 1 1	0 0 0	1 1 1	0/1 0/1 0/1	μPD1943G μPD1913C μPD6120C	
K51 K52 K53 K54 K55 K56				*		1 0 1 0 1	1 0 0 1 1	0 1 1 1 1	0 0 0 0	1 1 1 1 1	0 0 0	1 1 1 1	0/1 0/1 0/1 0/1	μPD1943G μPD1913C μPD6120C μPD6121G	
K51 K52 K53 K54 K55 K56 K57	*	*				1 0 1 0 1 0	1 0 1 1 0	0 1 1 1 1 0	0 0 0 0 0 1	1 1 1 1 1	0 0 0 0	1 1 1 1 1	0/1 0/1 0/1 0/1 0/1	μPD1943G μPD1913C μPD6120C μPD6121G μPD1943G μPD1943G	-
K51 K52 K53 K54 K55 K56 K57 K58			*			1 0 1 0 1 0 1	1 0 1 1 0 0	0 1 1 1 1 0 0	0 0 0 0 1 1	1 1 1 1 1 1 1	0 0 0 0 0	1 1 1 1 1 1	0/1 0/1 0/1 0/1 0/1 0/1	μPD1943G μPD1913C μPD6120C μPD6121G μPD1943G μPD1913C	-
K51 K52 K53 K54 K55 K56 K57 K58 K59		*			- KI/O₅	1 0 1 0 1 0 1 0	1 0 1 1 0 0 1	0 1 1 1 0 0 0	0 0 0 0 1 1 1	1 1 1 1 1 1 1 1	0 0 0 0 0 0	1 1 1 1 1 1 1	0/1 0/1 0/1 0/1 0/1 0/1 0/1	μPD1943G μPD1913C μPD6120C μPD6121G μPD1943G μPD1943G μPD1913C μPD6120C	
K51 K52 K53 K54 K55 K56 K57 K58 K59 K60		*	*	*	- KI/O₅	1 0 1 0 1 0 1	1 0 1 1 0 0	0 1 1 1 1 0 0	0 0 0 0 1 1	1 1 1 1 1 1 1	0 0 0 0 0	1 1 1 1 1 1	0/1 0/1 0/1 0/1 0/1 0/1	μPD1943G μPD1913C μPD6120C μPD6121G μPD1943G μPD1913C	
K51 K52 K53 K54 K55 K56 K57 K58 K59	*	*	*	*	- KI/O5 - KI/O6	1 0 1 0 1 0 1 0 1 0 1 0	1 0 1 1 0 0 1 1 1	0 1 1 1 0 0 0 0	0 0 0 1 1 1 1	1 1 1 1 1 1 1 1 1	0 0 0 0 0 0 0	1 1 1 1 1 1 1 1	0/1 0/1 0/1 0/1 0/1 0/1 0/1 0/1	μPD1943G μPD1913C μPD6120C μPD6121G μPD1943G μPD1913C μPD6120C μPD6121G μPD6121G μPD6121G μPD1943G μPD1943G μPD1913C	
K51 K52 K53 K54 K55 K56 K57 K58 K59 K60 K61	*	*	*	*	- KI/O₅	1 0 1 0 1 0 1 0 1 0	1 0 1 1 0 0 1 1 1 0	0 1 1 1 0 0 0 0 0 1	0 0 0 1 1 1 1 1 1	1 1 1 1 1 1 1 1 1 1	0 0 0 0 0 0 0 0 0	1 1 1 1 1 1 1 1 1	0/1 0/1 0/1 0/1 0/1 0/1 0/1 0/1 0/1	μPD1943G μPD1913C μPD6120C μPD6121G μPD1943G μPD1943G μPD1913C μPD6120C μPD6121G μPD6121G μPD1943G	

**Phase-out/Discontinued** 

Note Bit  $D_7$  is "0" when the SEL pin is connected to  $V_{DD}$ , and "1" when it is connected to  $V_{SS}$ .

#### 6. DOUBLE-INPUT OPERATION

All keys are provided with a multiple-input prevention circuit. When two or more keys are pressed simultaneously, no signal is transmitted; but when the keys K21 and K22, K21 and K23, or K21 and K24 are pressed together, D₅ is set to "1". However, the way keys are pressed determines the priority: If K22/K23/K24 are pressed 126 ms or longer after K21 is pressed, transmission is performed in this mode.

Double-input key operation is ideally suited for tape recording error prevention applications.

Phase-out/Discontinued

KEY	Do	D1	D2	D3	D4	D₅	D <sub>6</sub>	D7
K21 + K22	1	0	1	0	1	1	0	0/1
K21 + K23	0	1	1	0	1	1	0	0/1
K21 + K24	1	1	1	0	1	1	0	0/1

#### **Double-Input Operation Key Codes**

#### Double-Input Operation Timing

#### **1** Double-input transmission





#### (3) No operation

push



#### 7. ONE-SHOT/CONTINUOUS COMMAND TRANSMISSION MODE

#### 7.1 One-shot Command Transmission Mode

In order to reduce the average transmission current, the  $\mu$ PD6120C, 6121G, and 6122G transmit data only once, and thereafter transmit just the leader code and stop bit indicating that a key is depressed. As a result, this transmission method (one-shot command transmission mode) has the following characteristics.

#### Advantages

- Average transmission current is reduced to 1/3 to 1/4 compared with continuous command transmission mode
- Reduced software load for reception program (not all commands are processed all the time)
- This mode distinguishes when a key is pressed several times successively and when a key is kept depressed.

#### Disadvantages

- · If a command is not read the first time, it cannot be read a second time
- If a signal transmission is interrupted while continuous commands are executed, subsequent commands cannot be executed.

Moreover, when fosc = 455 kHz, the average current to the infrared-emitting diode is roughly equivalent to 3 % of the peak current.

 $I_{AVE} = (9 \text{ ms} + 0.56 \text{ ms})/108 \text{ ms} \times 1/3 \text{ (duty)} = 2.95 \% \text{ (first command is ignored)}$ 

#### 7.2 Continuous Command Transmission Mode

A continuous command transmission mode for transmitting data a second or more times is also available. As shown in Figure 7-2, it is possible to continuously transmit commands for all the keys or for individual key output lines simply by adding a diode D and connecting it to KI<sub>0</sub> or KI/O.

In this case, the average transmission current is larger than that in the one-shot command transmission mode. When fosc = 455 kHz, the average current to the infrared-emitting diode is roughly equivalent to 9 % of the peak current.

IAVE = (9 ms + 0.56 ms x 33)/108 ms x 1/3 (duty) = 8.48 %

- Cautions 1. If the double input key (K21-K24) is used in the continuous command transmission mode, double-input key transmission is not performed (D<sub>5</sub> does not become 1).
  - 2. When the voltage drop of the REM output is large, the signal is not transmitted accurately. Therefore, keep the REM output current within 1 mA.

Figure 7-1 shows the continuous command transmission mode.

Figure 7-1. Continuous Command Transmission Mode (When fosc = 455 kHz)

#### (1) μPD6120C, 6121G, 6122G



#### (2) µPD1913C, 1943G, 6102G

(1) K1 to K20, K33 to K52 (KO0 to KO4)



(2) K21 to K32, K53 to K64 (KO5 to KO7)



- **Note** In the case of the μPD1913C, 1943G and 6102G, the transmission repeat cycle (T) varies depending on the key.
- **Remark** I<sub>TYP</sub> = I<sub>AVE</sub> x I<sub>peak</sub> (LED) I<sub>AVE</sub> = (9 ms + 0.56 ms x 33)/T ms x 1/3 (duty)



- (1) Continuous command transmission for all keys<sup>Note 1</sup>
  - REM output is input to KIo with diode D.







Continuous command transmission can be performed for keys whose KI/O output lines have received diode D input<sup>Note 2</sup>.

Na

- Notes 1. Double-key transmission cannot be performed.
  - If the KI/O₅ output line (double-input key) is in the continuous command transmission mode, double-input key transmission is not performed (D₅ does not become 1).

Caution When the voltage drop of the REM output is large, the signal is not transmitted accurately. Therefore, keep the REM output current within 1 mA.

\*



#### 8. APPLICATION CIRCUIT EXAMPLE

#### (1) Example application circuit using $\mu$ PD6121



Phase-out/Discontinued

(2) Example application circuit using  $\mu$ PD6122





\* (3) Application circuit example, receive side



Note The  $\mu$ PC2801A's active level is high.

μ**PD6121, 6122** 

#### 9. ELECTRICAL SPECIFICATIONS

#### **Absolute Maximum Ratings** (T<sub>A</sub> = 25 °C)

Parameter	Symbol	Ratings	Unit
Supply voltage	Vdd	-0.3 to +6.0	V
Input voltage	Vı	-0.3 to V <sub>DD</sub> + 0.3	V
Power dissipation	PD	250	mW
Operating ambient temperature	TA	-20 to +75	°C
Storage temperature	Tstg	-40 to +125	°C

**Phase-out/Discontinued** 

#### **Recommended Operating Conditions** (T<sub>A</sub> = -20 to +75 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply voltage	Vdd	2.0	3.0	3.3	V
Oscillation frequency	fosc	400	455	500	kHz
Input voltage	Vı	0		Vdd	V
Custom code select pull-up resistor	Rup	160	200	240	kΩ

#### **DC Characteristics** (T<sub>A</sub> = 25 $^{\circ}$ C, V<sub>DD</sub> = 3.0 V)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply current 1	IDD1	fosc = 455 kHz		0.1	1	mA
Supply current 2	IDD2	fosc = STOP			1	μΑ
REM output current High	Іон1	Vo = 1.5 V	-5	-8		mA
REM output current Low	IOL1	Vo = 0.3 V	15	30		μΑ
LMP output current High	Іон2	Vo = 2.7 V	-15	-30		μΑ
LMP output current Low	IOL2	Vo = 0.3 V	1	1.5		mA
KI input current High	Іінт	VI = 3.0 V	10		30	μΑ
KI input current Low	lı∟ı	V1 = 0 V			-0.2	μΑ
KI, SEL input voltage High	VIH1		2.1		3.0	V
KI, SEL input voltage Low	VIL1		0		0.9	V
KI/O input voltage High	VIH2		1.3			V
KI/O input voltage Low	VIL2				0.4	V
KI/O input current High	Іін2	VI = 3.0 V	2		7	μΑ
KI/O input current Low	lil2	V1 = 0 V			-0.2	μΑ
KI/O output current High	Іонз	Vo = 2.5 V	-1.0		-2.5	mA
KI/O output current Low	Iol3	Vo = 1.7 V	35		100	μΑ
CCS input voltage High	Vінз		1.1			V
CCS input current High	Іінз	Pull-up, $V_1 = 3.0 V$			0.2	μA
CCS input current Low	li∟3	Pull-up, VI = 0 V	-3		-8	μΑ
CCS input current High	Іін4	Pull-down, VI = 3.0 V	10		30	μΑ
CCS input current Low	IIL4	Pull-down, VI = 0 V			-0.2	μΑ

Recommended Ceramic Resonators (T<sub>A</sub> = -20 to +75 °C, V<sub>DD</sub> = 2.0 to 3.3 V)

• μPD6121, 6122

Maker	Product	Recommende	d constant [pF]	Operating	voltage [V]
INIANCI	Tioddet	C1	C <sub>2</sub>	MIN.	MAX.
Murata Seisakusho Corp.	CSB455E	220	220	2.0	3.3
	CSB480E	220	220	2.0	3.3
Toko Corp.	CRK455	120	300	2.0	3.3
Kyocera Corp.	KBR-455BTLR	220	220	2.0	3.3

#### Example of external circuit



Caution If using an oscillation circuit, wire the area enclosed in the dotted line in the figure in the manner indicated below in order to avoid negative effects such as from stray capacitance of wires.

- Keep wiring as short as possible.
- Do not cross other signal lines. Do not design wiring close to lines with large fluctuating current.
- Make sure that the connection point of the oscillation circuit's capacitor has the same potential as V<sub>DD</sub>.
- Do not extract signals from the oscillation circuit.

### μ**PD6121, 6122**

\*

- **10. PACKAGE DRAWINGS**
- (1) Package for the  $\mu$ PD6121

#### 20 PIN PLASTIC SOP (375 mil)



detail of lead end







#### NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
A	13.00 MAX.	0.512 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	$0.016^{+0.004}_{-0.003}$
Е	0.125±0.075	$0.005 \pm 0.003$
F	2.9 MAX.	0.115 MAX.
G	2.50	0.098
Н	10.3±0.3	$0.406^{+0.012}_{-0.013}$
I	7.2	0.283
J	1.6	0.063
к	$0.15^{+0.10}_{-0.05}$	$0.006^{+0.004}_{-0.002}$
L	0.8±0.2	$0.031^{+0.009}_{-0.008}$
М	0.12	0.005
Ν	0.15	0.006
Р	3°+7° -3°	3° <sup>+7°</sup> -3°

P20GM-50-375B-4

# **Phase-out/Discontinued**

 $\star$  (2) Package for the  $\mu\text{PD6122}$ 

### 24 PIN PLASTIC SOP (375 mil)



#### NOTE

Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	INCHES
A	15.54 MAX.	0.612 MAX.
В	0.78 MAX.	0.031 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	$0.016^{+0.004}_{-0.003}$
Е	0.1±0.1	0.004±0.004
F	2.9 MAX.	0.115 MAX.
G	2.50	0.098
Н	10.3±0.3	$0.406^{+0.012}_{-0.013}$
I	7.2	0.283
J	1.6	0.063
к	$0.15^{+0.10}_{-0.05}$	$0.006^{+0.004}_{-0.002}$
L	0.8±0.2	$0.031\substack{+0.009\\-0.008}$
М	0.12	0.005
Ν	0.15	0.006
Р	3°+7° -3°	3°+7° -3°
		P24GM-50-375B-3





#### 11. RECOMMENDED SOLDERING CONDITIONS

The following conditions (see table below) must be met when soldering this product.

For more details, refer to the NEC document **SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (IEI-1207)**.

Please consult an NEC sales representative in case an other soldering process is used, or in case soldering is done under different conditions.

#### Table 11-1. Soldering Conditions for Surface Mounting

μPD6121G-001: 20-pin plastic SOP (375 mil) μPD6121G-002: 20-pin plastic SOP (375 mil) μPD6122G-001: 24-pin plastic SOP (375 mil) μPD6122G-002: 24-pin plastic SOP (375 mil)

Soldering Process	Soldering Conditions	Symbol
Infrared ray reflow	Peak temperature of package surface: 230 °C, Reflow time: 30 seconds or less (210 °C or higher), Number of reflow processes: 1	IR30-00-1
VPS	Peak temperature of package surface: 215 °C, Reflow time: 40 seconds or less (200 °C or higher), Number of reflow processes: 1	VP15-00-1
Wave soldering	Solder temperature: 260 °C or lower, Reflow time: 10 seconds or less, Number of reflow processes: 1 Preheat temperature: 120 °C or lower (at package surface)	WS60-00-1
Partial heating	Pin temperature: 300 °C or lower, Time: 3 seconds or less (per device side)	-

# Caution Do not apply more than one soldering method at any one time, except for the partial heating method.

#### \* APPENDIX. REMOTE CONTROL TRANSMISSION IC AND MICROCONTROLLER LIST

• Single-function remote control transmission ICs (NEC transmission format)

Part number Parameter	μPD6121	μPD6122				
Operating voltage	Vdd =	2.0 to 3.3 V				
Operating clock	fosc = 400 to 500 kHz ceramic resonator					
Transmission format	Leader 16-bit custom code 8-	bit data code 8-bit data code				
Modulation method	PPM 0 1					
	38-kHz carrier mo	dulation (fosc = 455 kHz)				
Custom code	16-	bit setting				
Data code	32 x 2	64 x 2				
No. of keys	32	64				
Package	20-pin SOP (375 mil)	24-pin SOP (375 mil)				

Cautions 1. New custom codes are not available for the following standard products.

 $\mu\text{PD6121G},$  6122G Ver II standard products (-002)

2. If products other than listed in Caution 1 are used, please contact NEC for custom codes.



• Single-Function 4-bit Single-Chip Microcontroller

Part number	μPD6133	μPD6134	μPD6604 <sup>Note 1</sup>				
Parameter							
ROM capacity	512 x 10 bits	1002 x 10 bits					
RAM capacity	32 x 4 bits						
Oscillator	Ceramic oscillator		RC oscillator				
S <sub>0</sub> (S-IN)	Read with Po1 register ( function provided)	Read with Pol register (left shift instruction excluded, standby cancellation function provided)					
S1/LED (S-OUT)	I/O (standby cancellation	on function provided)					
Key matrix (without Di)	8 x 6 = 48 keys						
Timer clock	fx/8, fx/16						
Stack	Also usable for RAM RF (1 level)						
Carrier frequency	fx, fx/8, fx/12, high level fx/2, fx/16, fx/24 (software specified)						
Instruction execution time	8 μs (fx = 1 MHz)						
Operating frequency	$f_x = 300 \text{ kHz to 1 MHz}$						
Power supply voltage	VDD = 1.8 to 3.6 V						
Operating ambient temperature	$T_{A} = -40$ to +85 °C						
Charge/discharge function (NOP)	Not provided (NOP inst	ruction provided)					
Low voltage detector	Low level is output to R	ESET pin at detection					
Package	• 20-pin plastic SOP	<ul><li> 20-pin plastic SOP</li><li> 20-pin plastic shrink DIP</li></ul>	<ul><li> 20-pin plastic SOP</li><li> 20-pin plastic shrink SOP</li></ul>				
PROM version	μPD61F35 (flash EEPR	OM <sup>™</sup> ) <sup>Note 2</sup>					

Notes 1. Under development

2. This product's pin configuration is the same as that of the 20-pin µPD6133, 6134, and 6604, but the package is a 24-pin SOP shrink DIP package.

Caution If using the NEC transmission format, please contact NEC for the custom code.



\* • 4-Bit Single-Chip Microcontroller for Programmable Remote Control Transmission

Part number Parameter	μPD6600	μPD6600A	μPD6124	μPD6124A	μPD6125A
ROM capacity	512 x 10 bits		1002 x 10 bits		
RAM capacity	32 x 5 bits				
Oscillator	Ceramic oscillator				
S <sub>0</sub> (S-IN)	Read with left shift instruction				
S1/LED (S-OUT)	Output				
Key matrix (without Di)	8 x 4 = 32 keys				8 x 8 = 64 keys
Timer clock	fx/8				
Stack	Also usable for RAM (3 levels)				
Carrier frequency	fx/8, fx/12 (mask option)				
Instruction execution time	16 μs (fx = 500 kHz)				
Operating frequency	fx = 400 kHz to 500 kHz				
Power supply voltage	VDD = 2.0 to 3.6 V	VDD = 2.2 to 3.6 V	VDD = 2.0 to 6.0 V	VDD = 2.2 to 5.5 V	VDD = 2.0 to 6.0 V
Operating ambient temperature	$T_{A} = -20 \text{ to } +75 \text{ °C}$				
Charge/discharge function (NOP)	Provided				
Low voltage detector	Not provided	Low level is output to S-OUT pin at detection	Not provided	Low level is ouput to S-OUT pin at detection	Not provided
Package	<ul> <li>20-pin plastic SOP</li> <li>20-pin plastic shrink DIP</li> </ul>				<ul> <li>24-pin plastic SOP</li> <li>24-pin plastic shrink DIP</li> </ul>
PROM version	μPD61P24 (one-time PROM)				_

Caution If using the NEC transmission format, please contact NEC for the custom code.

#### -NOTES FOR CMOS DEVICES –

Phase-out/Discontinued

#### **1** PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

#### **(2)** HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

#### **(3)** STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

# **Phase-out/Discontinued**

The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

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- Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
- Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
- Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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